

Correction

Correction: Jood, P. and Ohta, M. Hierarchical Architecturing for Layered Thermoelectric Sulfides and Chalcogenides. *Materials* 2015, 8, 1124–1149

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The authors wish to make the following corrections to this paper [1].

The authors regret that the lattice thermal conductivity (κ_{lat}) values of some samples in Table 1 and thermoelectric figure of merit (ZT) values of some samples in Table 2 were not correct. The tables with correct κ_{lat} and ZT values are shown below. The authors would like to apologize for any inconvenience caused.

Table 1. Seebeck coefficient (S), electrical resistivity (ρ), carrier mobility (μ), power factor (S^2/ρ), lattice thermal conductivity (κ_{lat}), and thermoelectric figure of merit (ZT) at room temperature in the in-plane (ab -plane) and out-of-plane (c -axis) directions for a single crystal of nearly stoichiometric TiS_2 [2] and polycrystalline $\text{Ti}_{1.008}\text{S}_2$ [3].

Sample	Direction	S ($\mu\text{V}\cdot\text{K}^{-1}$)	ρ ($\mu\Omega\text{ m}$)	μ ($\text{cm}^2\cdot\text{V}^{-1}\cdot\text{s}^{-1}$)	S^2/ρ ($\mu\text{W}\cdot\text{K}^{-2}\cdot\text{m}^{-1}$)	κ_{lat} ($\text{W}\cdot\text{K}^{-1}\cdot\text{m}^{-1}$)	ZT
Single crystal	In-plane	−251	17	15	3710	6.35	0.16
Single crystal	Out-of-plane	-	13,000	0.017	-	4.21	-
Polycrystalline	In-plane	−80	6.2	2.3	1030	2.0	0.12
Polycrystalline	Out-of-plane	−84	11	1.2	630	1.8	0.10

Table 2. Seebeck coefficient (S), electrical resistivity (ρ), total thermal conductivity (κ_{total}), lattice thermal conductivity (κ_{lat}), power factor (S^2/ρ), and thermoelectric figure of merit (ZT) in the in-plane (ab -plane) and out-of-plane (c -axis) directions of state-of-the-art misfit layered sulfides: $[\text{MS}]_{1+m}\text{TS}_2$ ($\text{M} = \text{La}, \text{Yb}; \text{T} = \text{Cr}, \text{Nb}$) [4,5].

Sample	Direction	T (K)	ρ ($\mu\Omega \cdot \text{m}$)	S ($\mu\text{V} \cdot \text{K}^{-1}$)	κ_{total} ($\text{W} \cdot \text{K}^{-1} \cdot \text{m}^{-1}$)	κ_{lat} ($\text{W} \cdot \text{K}^{-1} \cdot \text{m}^{-1}$)	S^2/ρ ($\mu\text{W} \cdot \text{K}^{-2} \cdot \text{m}^{-1}$)	ZT	Reference
$(\text{Yb}_2\text{S}_2)_{0.62}\text{NbS}_2$	In-plane	300	19.0	60	0.80	0.41	200	0.1	[5]
$(\text{La}_2\text{S}_2)_{0.62}\text{NbS}_2$	In-plane	300	11.5	22	-	-	50	-	[5]
$(\text{LaS})_{1.14}\text{NbS}_2^{\text{a}}$	In-plane	300	7.6	37	2.5	1.50	177	0.02	[4]
		950	22.0	83	2.00	0.93	316	0.15	
	Out-of-plane	300	13.3	25	2.04	1.48	49	0.01	
		950	32.1	72	1.62	0.88	162	0.09	
$(\text{LaS})_{1.14}\text{NbS}_2^{\text{b}}$	In-plane	300	5.2	35	4.88	3.45	233	0.02	[4]
		950	16.9	83	3.25	1.86	405	0.12	
	Out-of-plane	300	9.3	25	1.56	0.75	70	0.01	
		950	28.5	56	1.34	0.52	111	0.08	
$(\text{LaS})_{1.2}\text{CrS}_2^{\text{a}}$	In-plane	950	207	-172	1.16	1.04	143	0.11	[4]
	Out-of-plane	950	223	-174	1.02	0.91	137	0.13	
$(\text{LaS})_{1.2}\text{CrS}_2^{\text{b}}$	In-plane	950	171	-172	1.25	1.11	174	0.14	[4]
	Out-of-plane	950	278	-154	0.92	0.84	84	0.08	

^a Small grains ($\sim 1 \mu\text{m}$), weak/random orientation of grains; ^b Large grains ($>20 \mu\text{m}$), strong orientation of grains perpendicular to the pressing direction.

Conflicts of Interest

The authors declare no conflict of interest.

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